Hyperfast power diode

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	mb 	
2	А	anode	7 0 1	K — A 001aaa020
mb	mb	mounting base; connected to cathode	TO-220AC (SOD59)	001aaa020

6. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
BYC10-600	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59	

7. Marking

Table 4. Marking codes

Type number	Marking codes
BYC10-600	BYC10-600

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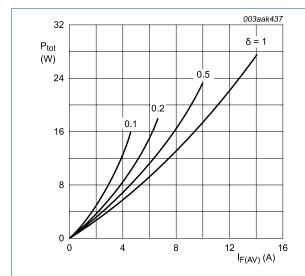
Hyperfast power diode

8. Limiting values

Table 5. Limiting values

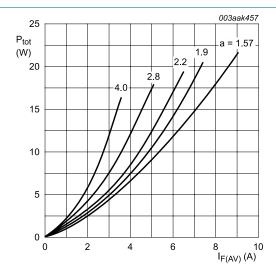
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		600	V
V_{RWM}	crest working reverse voltage		600	V
V_R	reverse voltage	T _{mb} ≤ 114 °C	500	V
$I_{F(AV)}$	average forward current	δ = 0.5 ; T _{mb} ≤ 78 °C; square-wave pulse; Fig. 1; Fig. 2	10	А
I _{FRM}	repetitive peak forward current	$\delta = 0.5$; $T_{mb} \le 78$ °C; square-wave pulse	20	А
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	65	Α
	forward current	t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	71	А
T _{stg}	storage temperature		-40 to 150	°C
Tj	junction temperature		150	°C



 $I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$ $V_o = 1.300 \text{ V}; R_s = 0.050 \Omega$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 1.300 V; R_s = 0.050 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

Hyperfast power diode

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 3	-	-	2	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

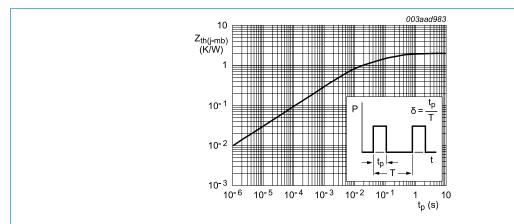


Fig. 3. Transient thermal impedance from junction to mounting base as a function of pulse width

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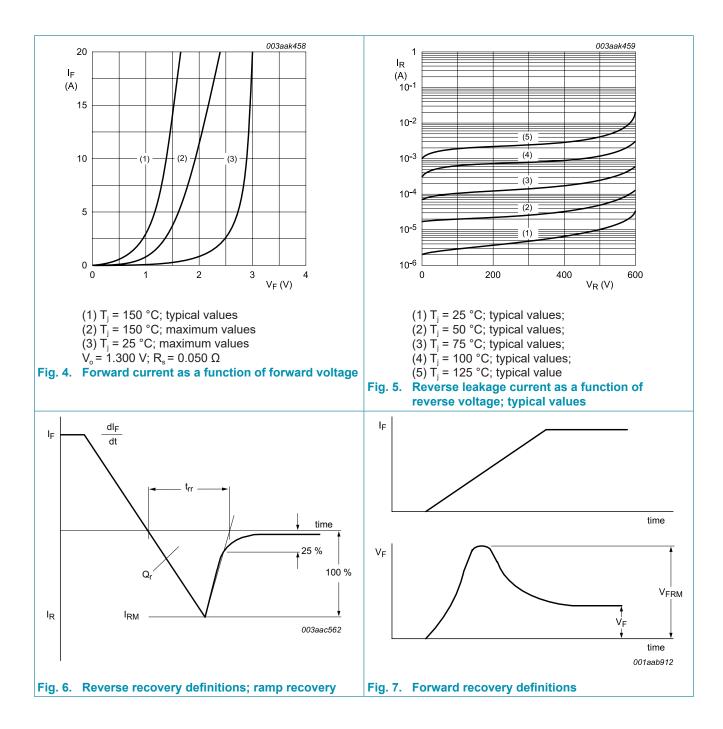
Hyperfast power diode

10. Characteristics

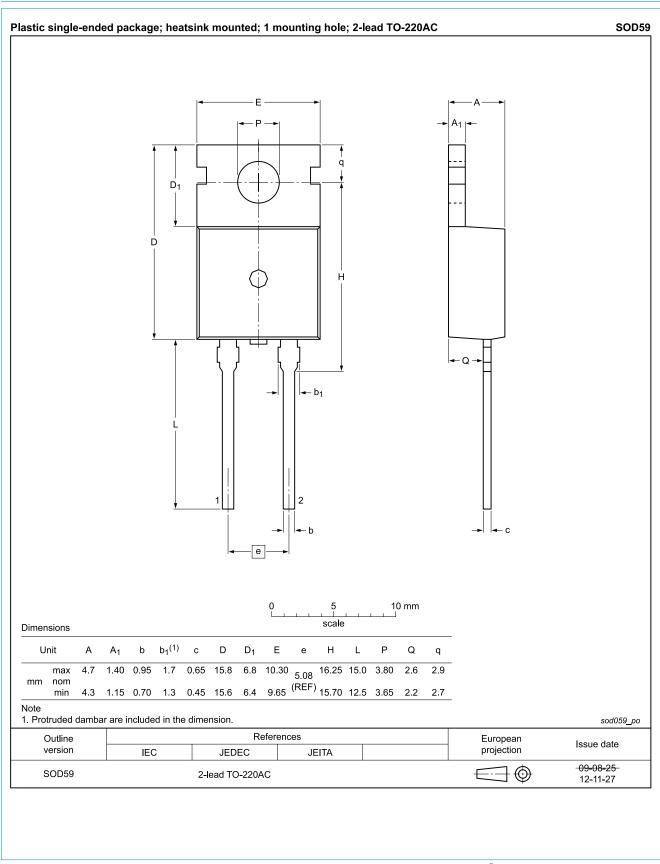
Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V_{F}	forward voltage	I _F = 10A; T _j = 25 °C; <u>Fig. 4</u>	-	2	2.9	V
		I _F = 10 A; T _j = 150 °C; <u>Fig. 4</u>	-	1.4	1.8	V
		I _F = 20 A; T _j = 150 °C; <u>Fig. 4</u>	-	1.7	2.3	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C; <u>Fig. 5</u>	-	9	200	μA
		V _R = 500 V; T _j = 100 °C; <u>Fig. 5</u>	-	1.1	3	mA
Dynamic	characteristics			1	,	
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 6$	-	35	55	ns
		$I_F = 10 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 6$	-	19	-	ns
		$I_F = 10 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 100 \text{ °C}; Fig. 6$	-	32	40	ns
I _{RM}	peak reverse recovery current	$I_F = 10 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 100 \text{ A}/\mu\text{s};$ $T_j = 125 ^{\circ}\text{C}; Fig. 6$	-	3	7.5	А
		$I_F = 10 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 6$	-	9.5	12	А
V _{FRM}	forward recovery voltage	$I_F = 10 \text{ A}; \text{ dI}_F/\text{dt} = 100 \text{ A/}\mu\text{s}; T_j = 25 °C; Fig. 7$	-	8	11	V

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11. Package outline



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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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